

# NSM80100MT1G

## PNP Transistor with Dual Series Switching Diode

### Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### Typical Applications

- LCD Control Board
- High Speed Switching
- High Voltage Switching

### MAXIMUM RATINGS – PNP TRANSISTOR

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	$V_{CEO}$	-80	Vdc
Collector – Base Voltage	$V_{CBO}$	-80	Vdc
Emitter – Base Voltage	$V_{EBO}$	-4.0	Vdc
Collector Current – Continuous	$I_C$	-500	mAdc

### MAXIMUM RATINGS – SWITCHING DIODE

Rating	Symbol	Value	Unit
Peak Reverse Voltage	$V_R$	100	V
Peak Forward Current	$I_F$	200	mA
Peak Forward Surge Current $t < 1$ sec $t = 1$ $\mu$ sec	$I_{FSM}$	1.0 20	A
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150	$^{\circ}C$

### THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) @ $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	$P_D$	400	mW mW/ $^{\circ}C$
Thermal Resistance from Junction-to-Ambient (Note 1)	$R_{\theta JA}$	313	$^{\circ}C/W$
Total Device Dissipation FR-5 Board (Note 2) $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	$P_D$	270	mW mW/ $^{\circ}C$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	463	$^{\circ}C/W$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^{\circ}C$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

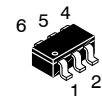
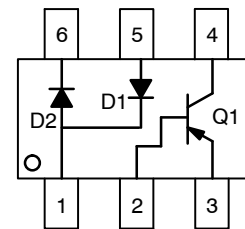
1. FR-5 = 650 mm<sup>2</sup> pad, 2.0 oz Cu.
2. FR-5 = 10 mm<sup>2</sup> pad, 2.0 oz Cu.



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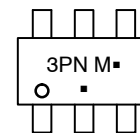
<http://onsemi.com>

## PNP Transistor with Dual Series Switching Diode



SC-74  
CASE 318F

### MARKING DIAGRAM



3PN = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)  
\*Date Code orientation may vary depending upon manufacturing location.

### ORDERING INFORMATION

Device	Package	Shipping†
NSM80100MT1G	SC-74 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NSM80100MT1G

## Q1: PNP TRANSISTOR

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector - Emitter Breakdown Voltage (Note 3) $(I_C = -1.0 \text{ mA}, I_B = 0)$	$V_{(BR)CEO}$	-80	-	V
Emitter - Base Breakdown Voltage $(I_E = -100 \mu\text{A}, I_C = 0)$	$V_{(BR)EBO}$	-4.0	-	V
Collector Cutoff Current $(V_{CE} = -60 \text{ V}, I_B = 0)$	$I_{CES}$	-	-0.1	$\mu\text{A}$
Collector Cutoff Current $(V_{CB} = -80 \text{ V}, I_E = 0)$	$I_{CBO}$	-	-0.1	$\mu\text{A}$

### ON CHARACTERISTICS (Note 3)

DC Current Gain $(I_C = -10 \text{ mA}, V_{CE} = -1.0 \text{ V})$	$h_{FE}$	120	-	-
Collector - Emitter Saturation Voltage $(I_C = -100 \text{ mA}, I_B = -10 \text{ mA})$	$V_{CE(sat)}$	-	-0.25	V
Base - Emitter Saturation Voltage $(I_C = -100 \text{ mA}, V_{CE} = -1.0 \text{ V})$	$V_{BE(sat)}$	-	-1.2	V

### SMALL-SIGNAL CHARACTERISTICS

Current - Gain - Bandwidth Product (Note 4) $(I_C = -100 \text{ mA}, V_{CE} = -2.0 \text{ V}, f = 100 \text{ MHz})$	$f_T$	150	-	MHz
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3. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

4.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

## D1, D2: SWITCHING DIODE ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Reverse Breakdown Voltage	$V_{(BR)}$	75	-	V
Reverse Voltage Leakage Current $(V_R = 75 \text{ V})$ $(V_R = 20 \text{ V}, T_J = 150^\circ\text{C})$ $(V_R = 75 \text{ V}, T_J = 150^\circ\text{C})$	$I_R$	-	1.0 30 100	$\mu\text{A}$
Diode Capacitance $(V_R = 0 \text{ V}, f = 1.0 \text{ MHz})$	$C_D$	-	1.5	pF
Forward Voltage $(I_F = 1.0 \text{ mA})$ $(I_F = 10 \text{ mA})$ $(I_F = 50 \text{ mA})$ $(I_F = 150 \text{ mA})$	$V_F$	-	715 855 1000 1250	mV
Reverse Recovery Time $(I_F = I_R = 10 \text{ mA}, i_{R(REC)} = 1.0 \text{ mA}, R_L = 100 \Omega)$	$t_{rr}$	-	4.0	ns
Forward Recovery Voltage $(I_F = 10 \text{ mA}, t_r = 20 \text{ ns})$	$V_{FR}$	-	1.75	V

# N5M80100MT1G

## TYPICAL CHARACTERISTICS

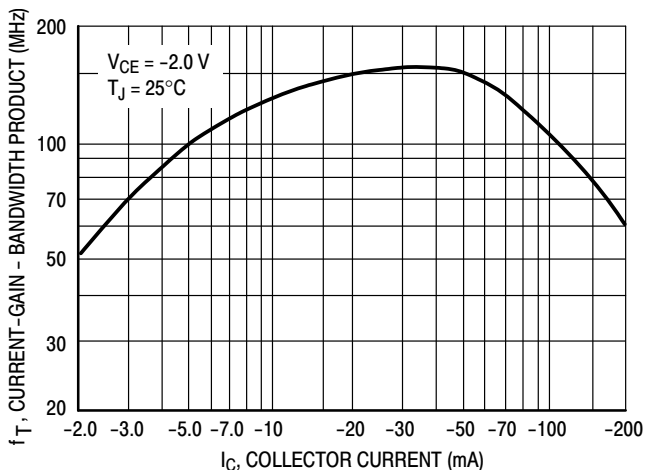


Figure 1. Current-Gain — Bandwidth Product

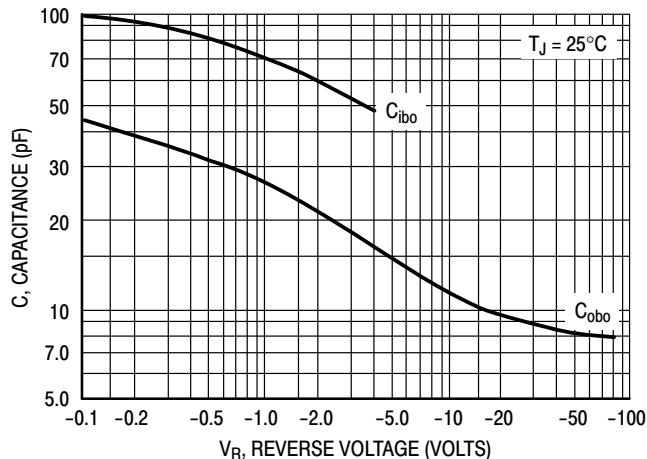


Figure 2. Capacitance

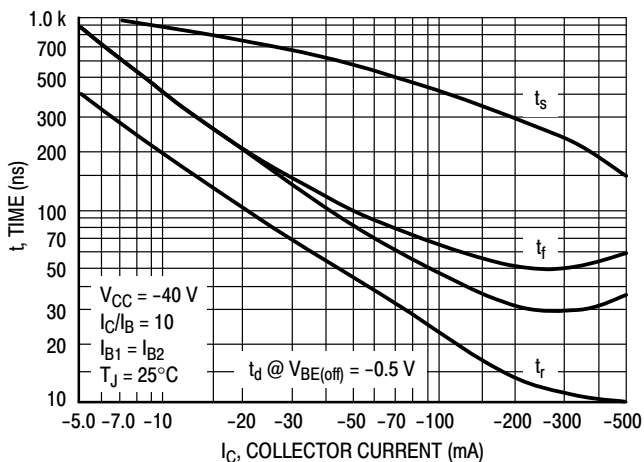


Figure 3. Switching Time

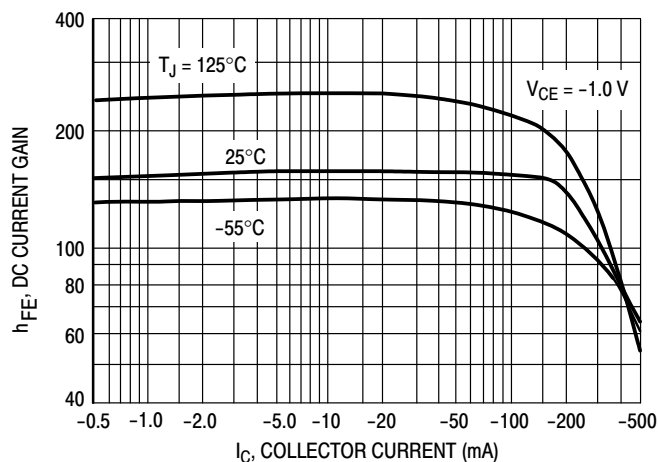


Figure 4. DC Current Gain

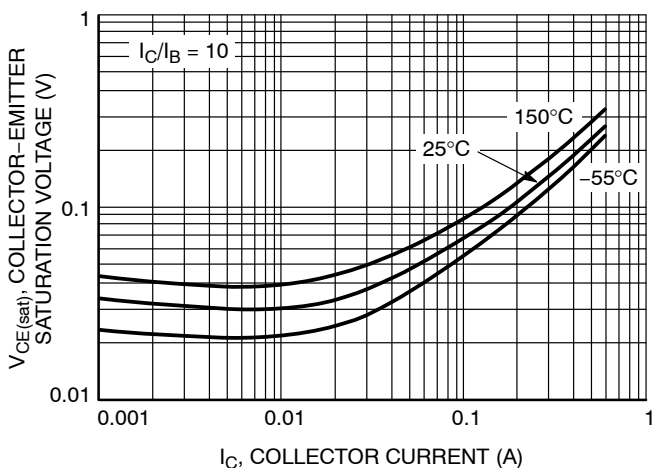


Figure 5. Collector Emitter Saturation Voltage vs. Collector Current

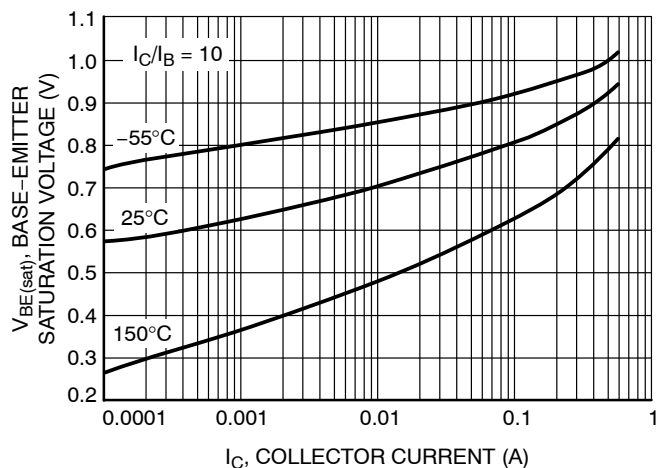
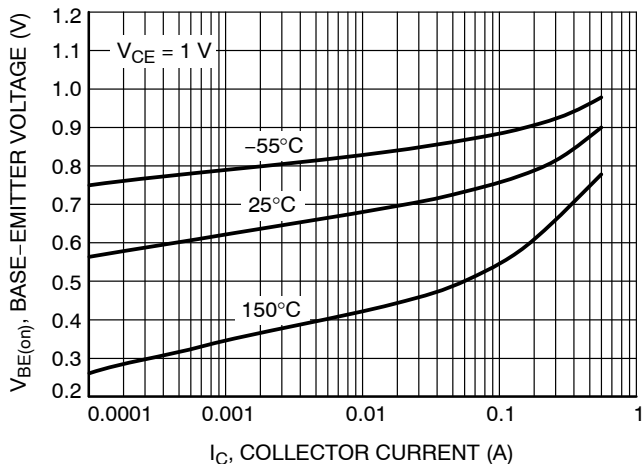


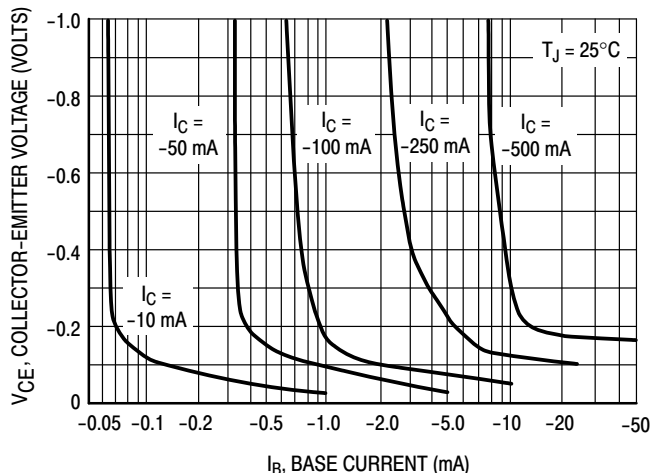
Figure 6. Base Emitter Saturation Voltage vs. Collector Current

# NSM80100MT1G

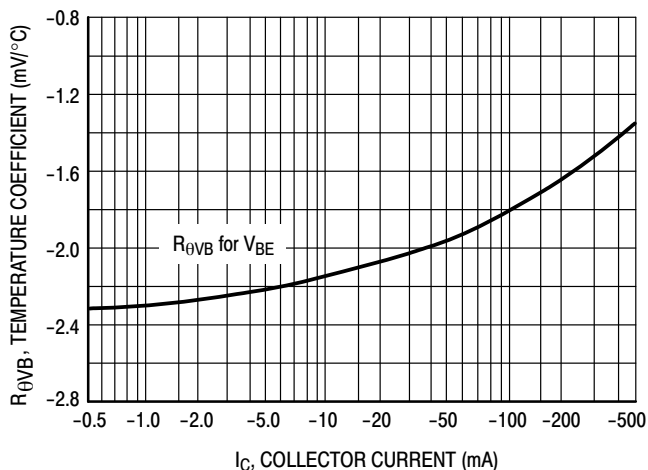
## TYPICAL CHARACTERISTICS



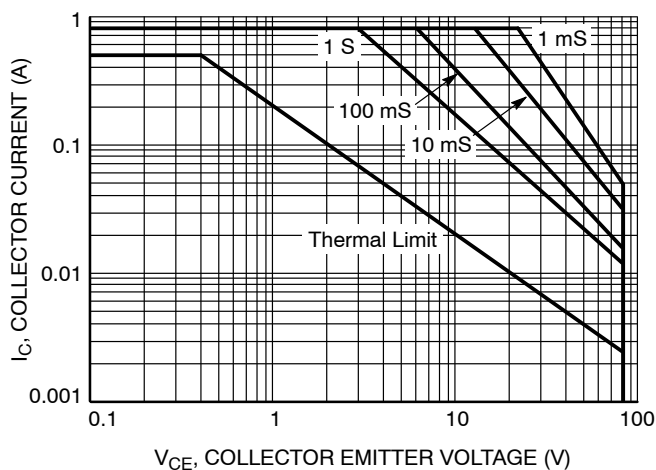
**Figure 7. Base-Emitter Voltage vs. Collector Current**



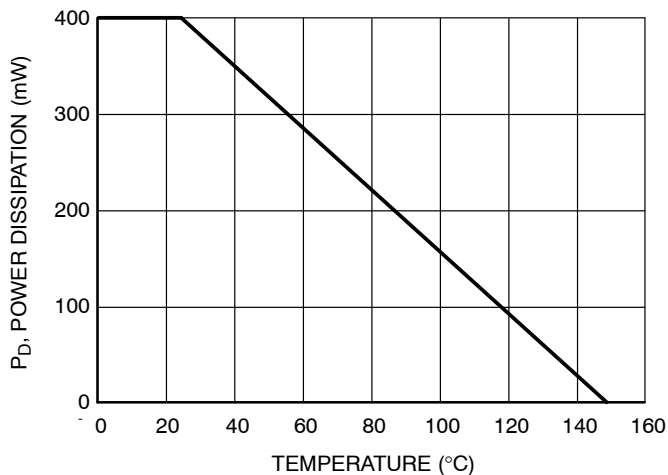
**Figure 8. Collector Saturation Region**



**Figure 9. Base-Emitter Temperature Coefficient**



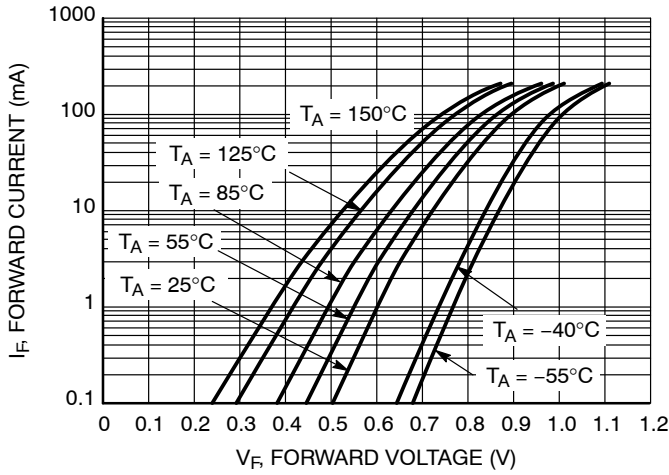
**Figure 10. Safe Operating Area**



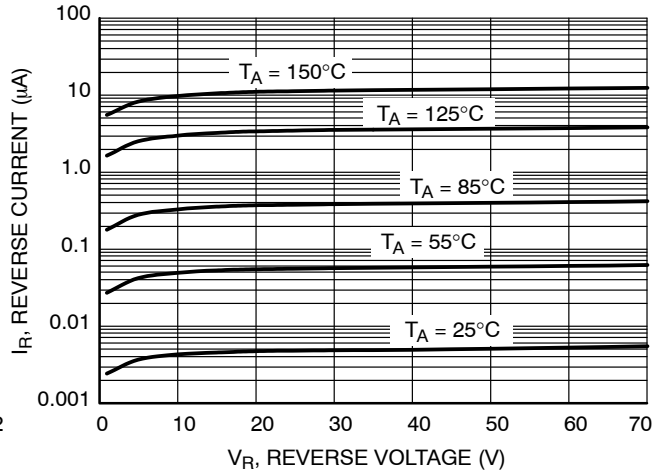
**Figure 11. Operating Temperature Derating**

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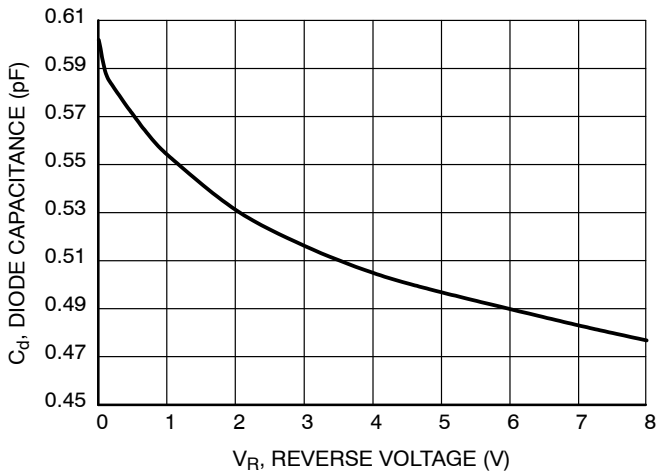
## TYPICAL CHARACTERISTICS



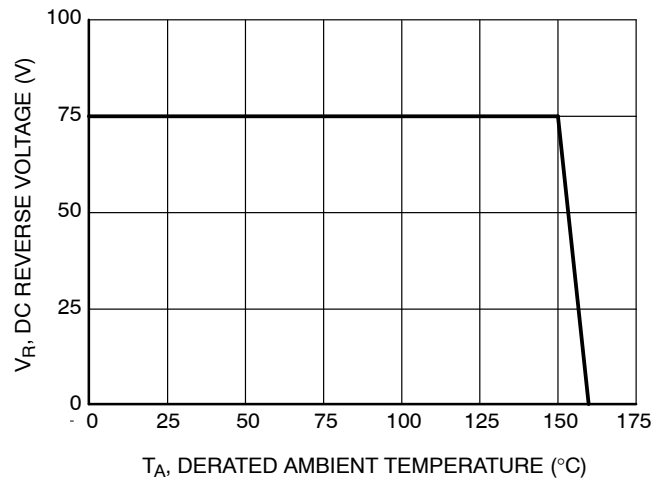
**Figure 12. Forward Voltage**



**Figure 13. Leakage Current**



**Figure 14. Capacitance**

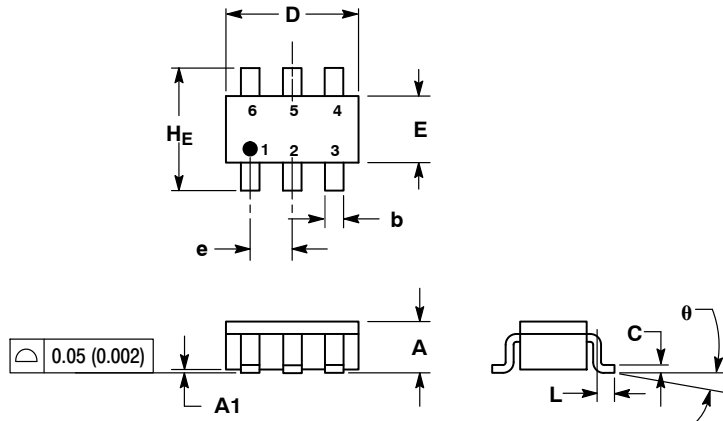


**Figure 15. Diode Power Dissipation Curve**

# NSM80100MT1G

## PACKAGE DIMENSIONS

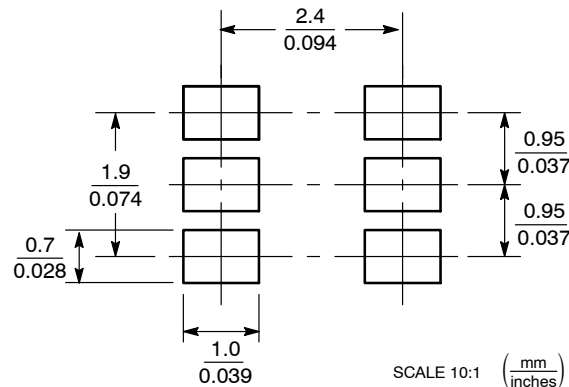
SC-74  
CASE 318F-05  
ISSUE M



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  4. 318F-01, -02, -03 OBSOLETE. NEW STANDARD 318F-04.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
c	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
theta	0°	-	10°	0°	-	10°

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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